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VS-VSKD600..PbF

Vishay Semiconductors

Standard Diodes (Super MAGN-A-PAK Power Modules), 600 A



Super MAGN-A-PAK

FEATURES

- High current capability
- High surge capability
- High voltage ratings up to 2000 V
- \bullet 3000 V_{RMS} isolating voltage with non-toxic substrate
- Industrial standard package
- UL approved file E78996
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Rectifying bridge for large motor drives
- Rectifying bridge for large UPS

| PRIMARY CHARACTERISTICS | | | | | |
|-------------------------|-------------------------------|--|--|--|--|
| I _{F(AV)} | 600 A | | | | |
| Туре | Modules - diode, high voltage | | | | |
| Package | Super MAGN-A-PAK | | | | |
| Circuit configuration | Two diodes doubler circuit | | | | |

| MAJOR RATINGS AND CHARACTERISTICS | | | | | |
|-----------------------------------|-----------------|-------------|---------------------|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | |
| | | 600 | A | | |
| I _{F(AV)} | T _C | 100 | °C | | |
| 1 | | 942 | A | | |
| I _F (RMS) | T _C | 100 | °C | | |
| IFSM | 50 Hz | 19 000 | • | | |
| | 60 Hz | 20 100 | — A | | |
| l ² t | 50 Hz | 1805 | – kA ² s | | |
| 1-1 | 60 Hz | 1683 | KA-S | | |
| l²√t | | 18 050 | kA²√s | | |
| V _{RRM} | Range | 800 to 2000 | V | | |
| T _{Stg} , T _J | Range | -40 to +150 | °C | | |

ELECTRICAL SPECIFICATIONS

| VOLTAGE RATINGS | | | | | | | | |
|-----------------|-----------------|--|--|---|--|--|--|--|
| TYPE NUMBER | VOLTAGE CODE | V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | I _{RRM} MAXIMUM AT T _J MAXIMUM mA | | | | |
| | 08 | 800 | 900 | | | | | |
| VS-VSKD600 | 12 | 1200 | 1300 | 50 | | | | |
| V3-V3ND000 | 16 | 1600 | 1700 | 50 | | | | |
| | 20 | 2000 | 2100 | | | | | |

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| FORWARD CONDUCTION | | | | | | |
|--|---------------------|--|------------------------------|--|--------|---------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | | VALUES | UNITS |
| Maximum average forward current | | 180° conduction, half sine wave | | | 600 | А |
| at case temperature | I _{F(AV)} | | uction, nan sine | e wave | 100 | °C |
| Maximum RMS forward current | I _{F(RMS)} | 180° condu | uction, half sine | e wave at T _C = 100 °C | 942 | А |
| | | t = 10 ms | No voltage | | 19.0 | |
| Maximum peak, one-cycle forward, | l | t = 8.3 ms | reapplied | | 20.1 | kA |
| non-repetitive surge current | IFSM | t = 10 ms | 100 % V _{RRM} | Sinusoidal half wave, initial $T_J = T_J$ maximum | 16.2 | |
| | | t = 8.3 ms | reapplied | | 17.2 | |
| | l ² t | t = 10 ms | No voltage | | 1805 | - kA ² s |
| Movimum 12t for fusing | | t = 8.3 ms | reapplied | | 1683 | |
| Maximum I ² t for fusing | | t = 10 ms | 100 % V _{RRM} | | 1319 | |
| | | t = 8.3 ms | reapplied | | 1230 | |
| Maximum I ² √t for fusing | l²√t | t = 0.1 ms | to 10 ms, no vo | oltage reapplied | 18 050 | kA²√s |
| Low level value of threshold voltage | V _{F(TO)1} | $(16.7 \% x \pi x I_{F(AV)} < I < \pi x I_{F(AV)}), T_J = T_J maximum$ | | | 0.70 | v |
| High level value of threshold voltage | V _{F(TO)2} | $(I > \pi x I_{F(AV)}), T_J = T_J maximum$ | | | 0.77 | v |
| Low level value of forward slope resistance | r _{f1} | $(16.7 \% x \pi x I_{F(AV)} < I < \pi x I_{F(AV)}), T_J = T_J \text{ maximum}$ | | | 0.28 | |
| High level value of forward slope resistance | r _{f2} | $(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$ 0.2 | | | 0.25 | mΩ |
| Maximum forward voltage drop | V _{FM} | I _{pk} = 1800 | A, T _J = 25 °C, t | _p = 10 ms sine pulse | 1.45 | V |

| BLOCKING | | | | | |
|--|------------------|--|--------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| RMS insulation voltage | V _{INS} | t = 1 s | 3000 | V | |
| Maximum peak reverse and off-state leakage current | I _{RRM} | $T_J = T_J$ maximum, rated V_{RRM} applied | 50 | mA | |

| THERMAL AND MECHANICAL SPECIFICATIONS | | | | | | |
|--|-----------------------------------|--|-------------|---------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Maximum junction operating and storage temperature range | T _J , T _{Stg} | | -40 to +150 | °C | | |
| Maximum thermal resistance, junction to case per junction | R _{thJC} | DC operation | 0.065 | K/W | | |
| Maximum thermal resistance, case to heatsink per module | R _{thC-hs} | Mounting surface smooth, flat and greased | 0.02 | r∕ vv | | |
| Mounting Super MAGN-A-PAK to heatsink | | A mounting compound is recommended and the | 6 to 8 | | | |
| torque ± 10 % busbar to Super MAGN-A-PAK | | torque should be rechecked after a period of 3 hours to allow for the spread of the compound | 12 to 15 | Nm | | |
| Approximate weight | | | 1500 | g | | |
| Case style | | See dimensions - link at the end of datasheet Super MA | | I-A-PAK | | |

| | N | | | |
|------------------|-----------------------|------------------------|---------------------|-------|
| CONDUCTION ANGLE | SINUSOIDAL CONDUCTION | RECTANGULAR CONDUCTION | TEST CONDITIONS | UNITS |
| 180° | 0.009 | 0.006 | | |
| 120° | 0.011 | 0.011 | | |
| 90° | 0.014 | 0.015 | $T_J = T_J$ maximum | K/W |
| 60° | 0.021 | 0.022 | | |
| 30° | 0.037 | 0.038 | | |

Note

• The table above shows the increment of thermal resistance RthJC when devices operate at different conduction angles than DC

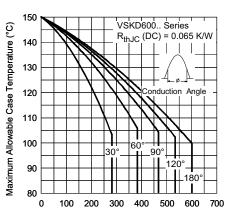
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Average Forward Current (A)

Fig. 1 - Current Ratings Characteristics

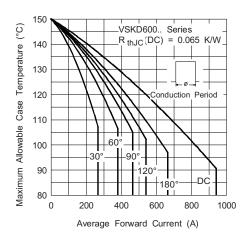


Fig. 2 - Current Ratings Characteristics

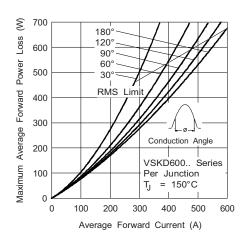


Fig. 3 - Forward Power Loss Characteristics

§ 1000 DC Loss 900 180 120 800 Maximum Average Forward Power 90 60 700 30 600 500 RMS 400 Conduction Period 300 VSKD600.. Series 200 Per Junction 100 = 150°C ТJ 0 0 200 400 600 800 1000 Average Forward Current (A)

Fig. 4 - Forward Power Loss Characteristics

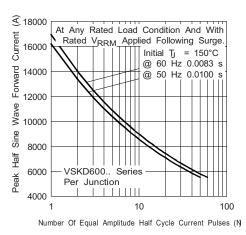


Fig. 5 - Maximum Non-Repetitive Surge Current

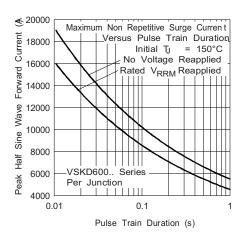


Fig. 6 - Maximum Non-Repetitive Surge Current

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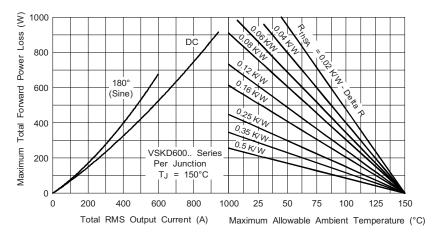


Fig. 7 - Forward Power Loss Characteristics

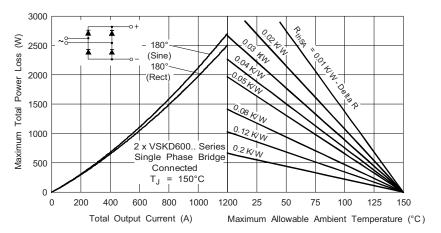


Fig. 8 - Forward Power Loss Characteristics

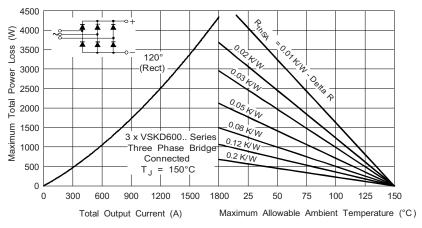


Fig. 9 - Forward Power Loss Characteristics

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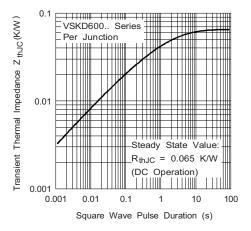


Fig. 10 - Thermal Impedance Z_{thJC} Characteristic

ORDERING INFORMATION TABLE

| Device code | VS-VS | KD | 600 | - | 20 | PbF | |
|-------------|---|------|-----------|---------------------------------|----------|-----------------------|--------------|
| | | 2 | 3 | | 4 | 5 | |
| | 1 - 2 - | Circ | cuit conf | niconduo iguratio configu | n D = tv | vo diod | es in series |
| | Gurrent rating Voltage code x 100 = V_{RRM} (see voltage ratings Lead (Pb)-free | | | | | oltage ratings table) | |

| CIRCUIT CONFIGURATION | | | | | |
|----------------------------|-------------------------------|-----------------|--|--|--|
| CIRCUIT DESCRIPTION | CIRCUIT CONFIGURATION CODE | CIRCUIT DRAWING | | | |
| Two diodes doubler circuit | KD | | | | |

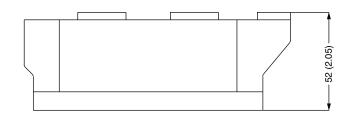
| LINKS TO RELATED DOCUMENTS | | | | |
|----------------------------|--------------------------|--|--|--|
| Dimensions | www.vishay.com/doc?95088 | | | |

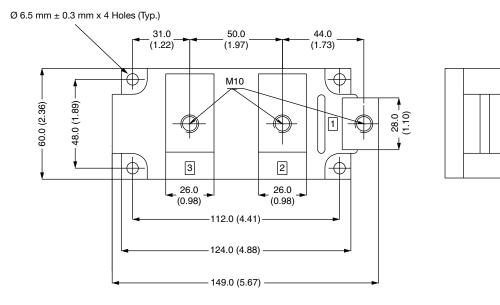


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Super MAGN-A-PAK Diode

DIMENSIONS in millimeters (inches)





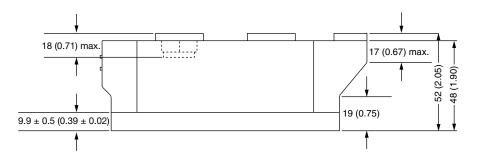
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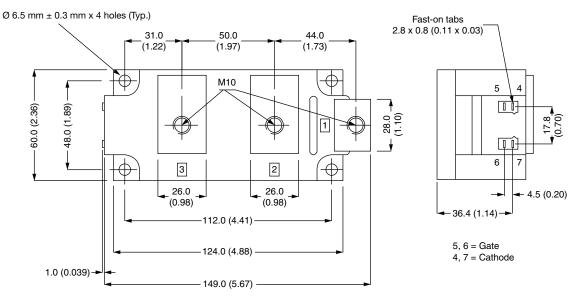


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Super MAGN-A-PAK Thyristor/Diode

DIMENSIONS in millimeters (inches)







Vishay

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